

Electronic supplementary information (ESI)

Ab-initio study on the two-dimensional anisotropic monolayers ScXY (X =S, Se; Y = Cl, Br) for the photocatalytic water splitting applications with high carrier mobilities

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Table S1. The calculated linear elastic constants of the ScXY monolayers

Material	C_{11}	C_{12}	C_{22}	C_{66}
ScSCl	90.843	12.574	71.150	20.896
ScSBr	86.886	12.602	66.654	20.822
ScSeCl	84.166	10.652	64.543	18.307
ScSeBr	80.449	10.063	60.441	18.024

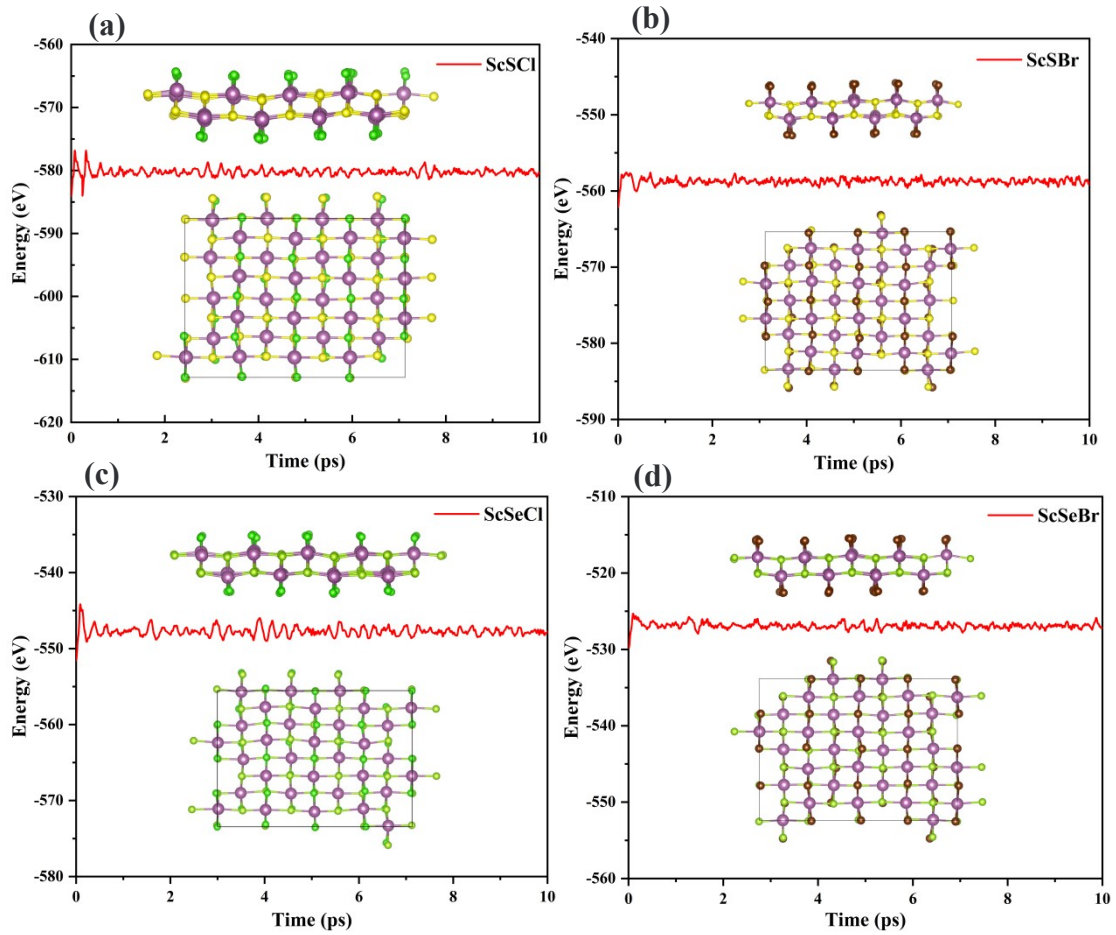
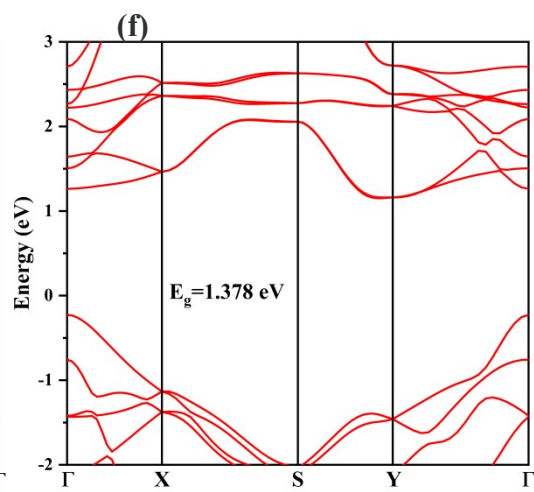
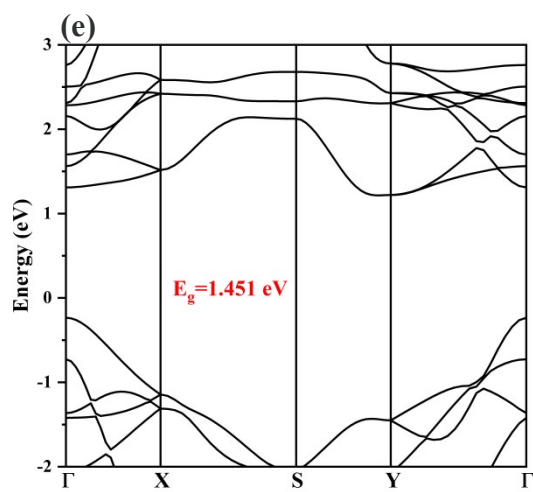
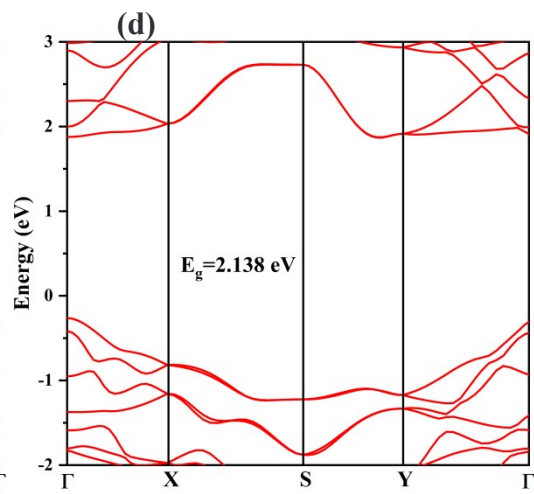
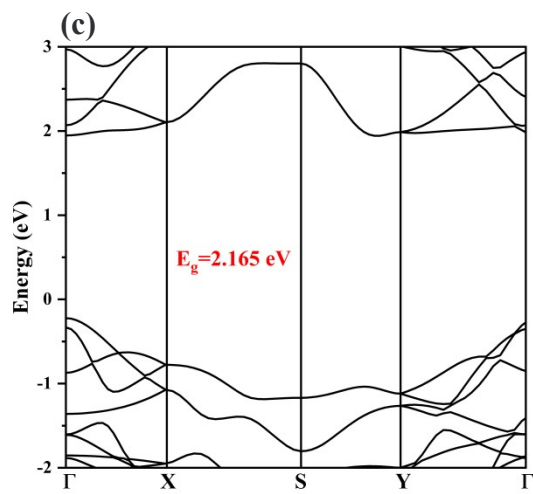
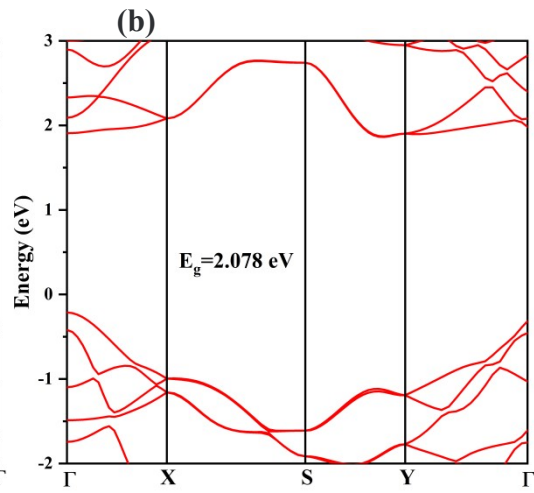
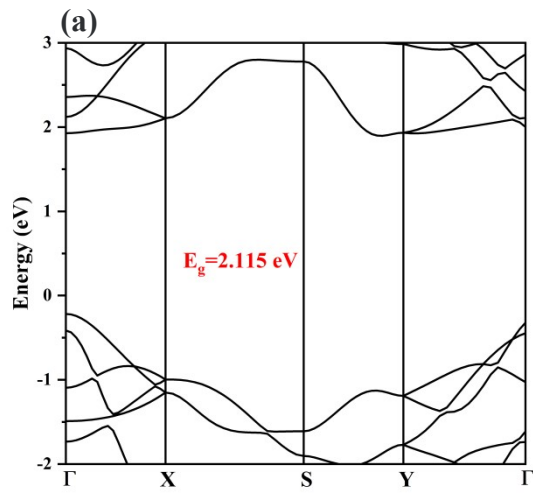


Fig. S1. The energy fluctuation of ScSCl (a), ScSBr (b), ScSeCl (c), and ScSeBr (d) monolayers throughout the simulation. A $4 \times 4 \times 1$ supercell was selected to carry out the AIMD simulation, no enormous fluctuations are found in energy at 300 K, suggesting that these four monolayers are thermally stable.



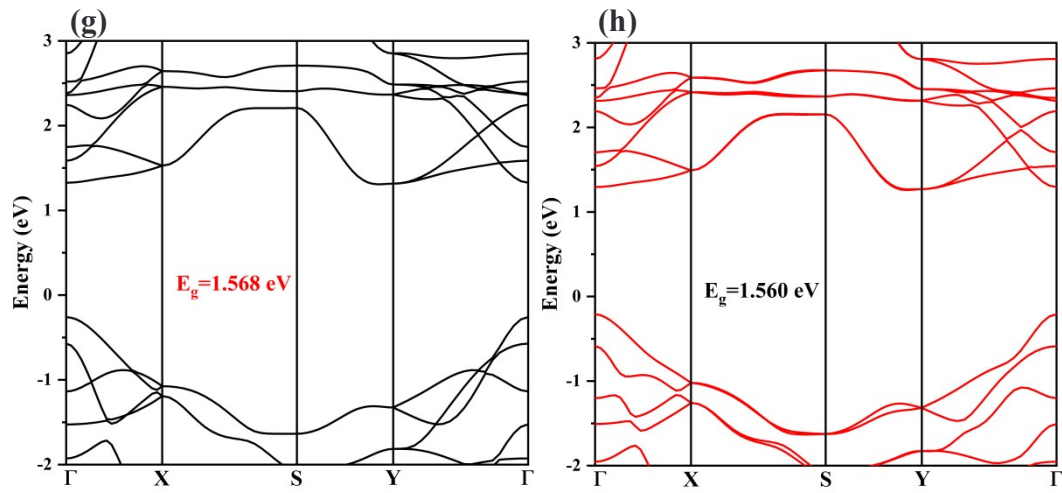


Fig. S2. The band structure of the ScXY (X=S, Se; Y=Cl, Br) monolayers calculated from the PBE level. (a, c, e, g) is obtained from pure PBE for monolayer ScSCl, ScSBr, ScSeCl, and ScSeBr, respectively, and (b, d, f, h) is the corresponding result from PBE with SOC.

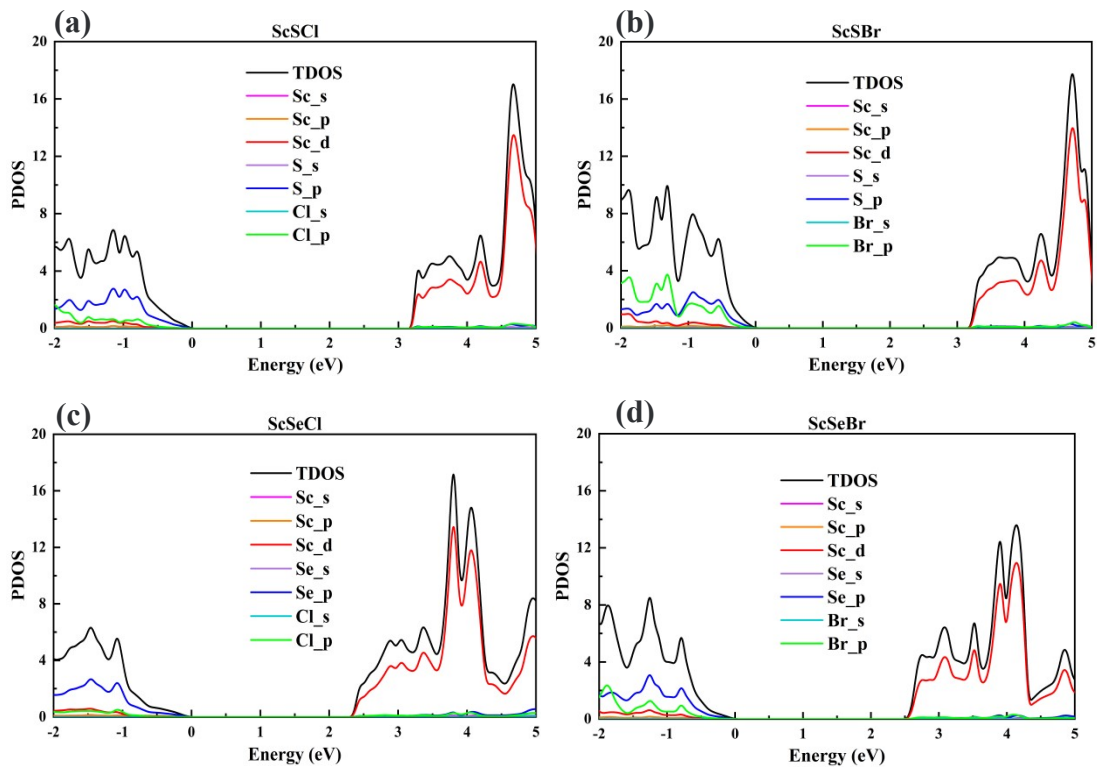


Fig. S3. The calculated partial density of state of ScSCl (a), ScSBr (b), ScSeCl (c), and ScSeBr (d) monolayers at the HSE06 level.

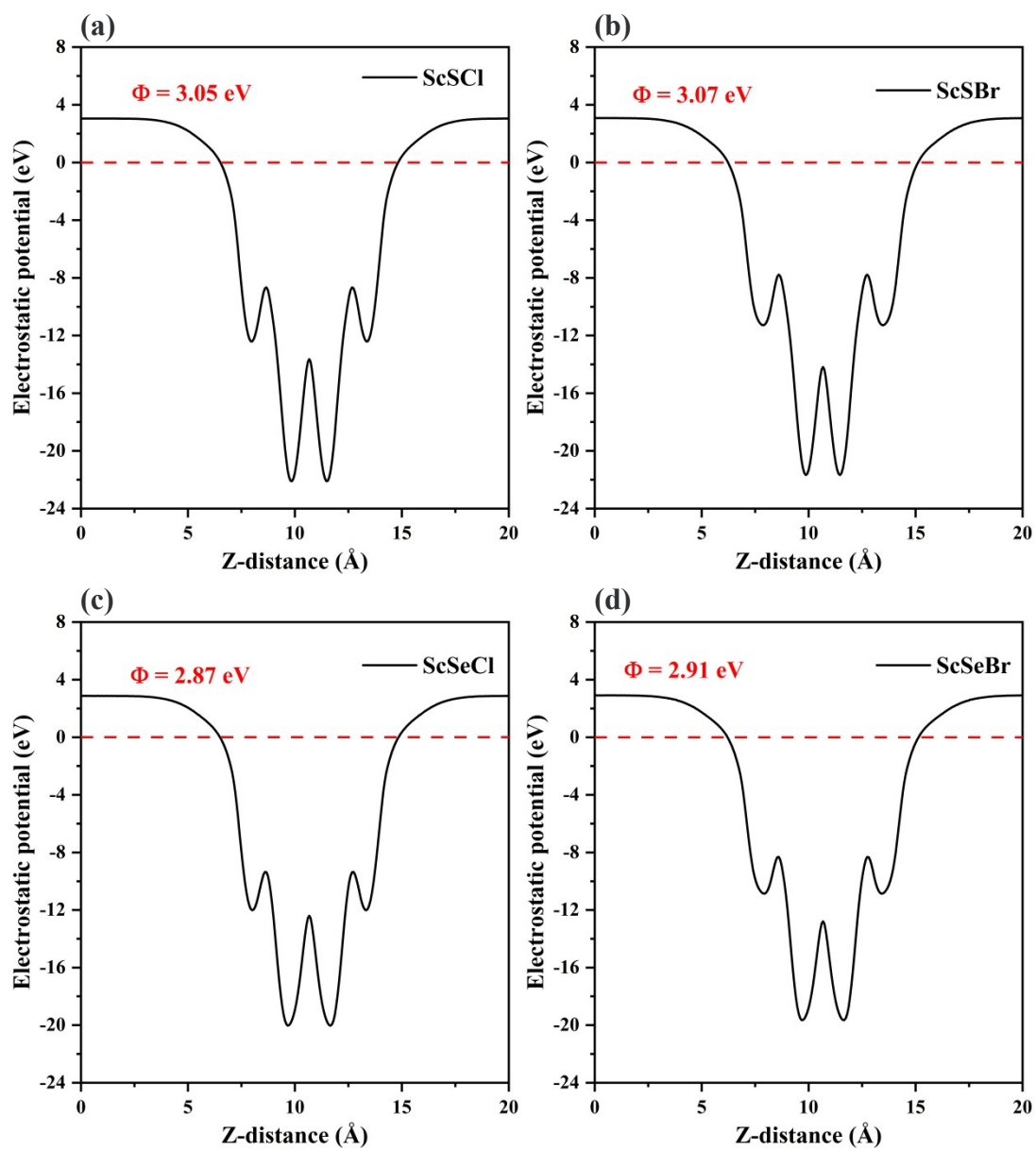


Fig. S4. The calculated average electrostatic potential for ScSCl (a), ScSBr (b), ScSeCl (c), and ScSeBr (d) monolayers with HSE06 functional.

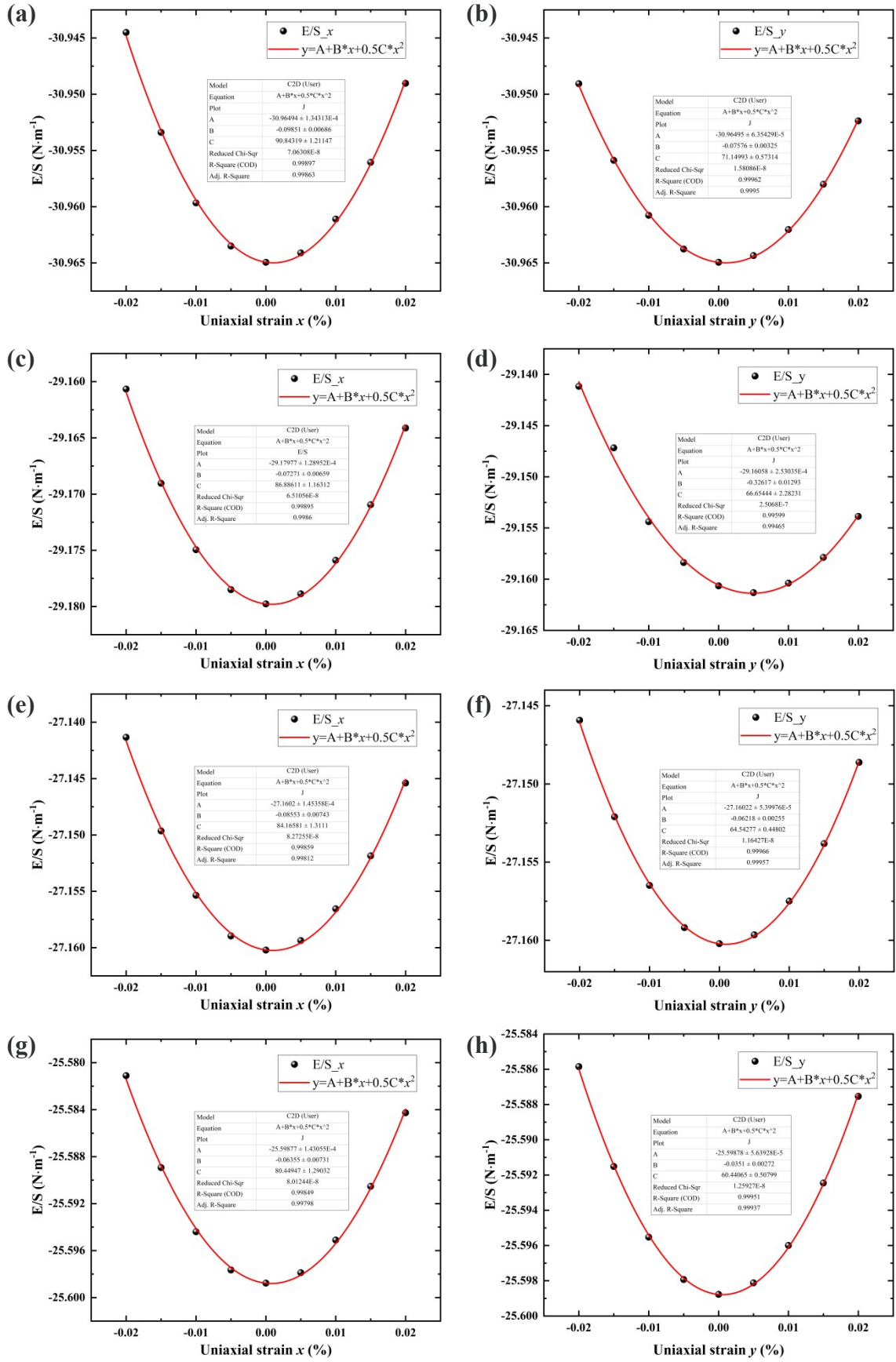
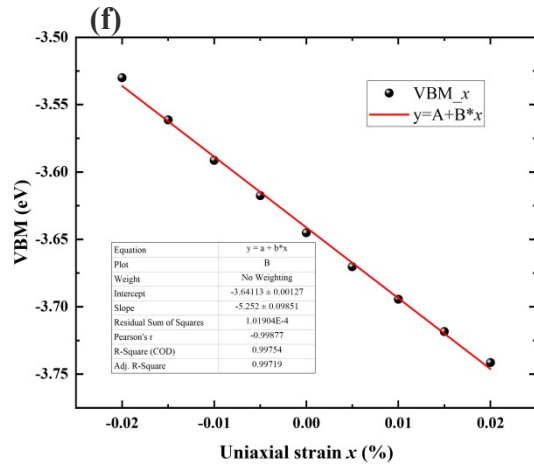
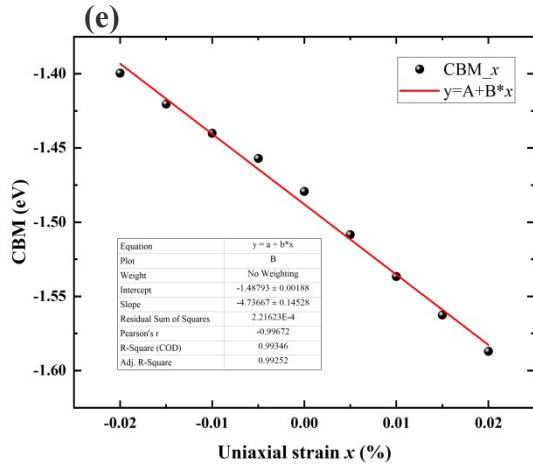
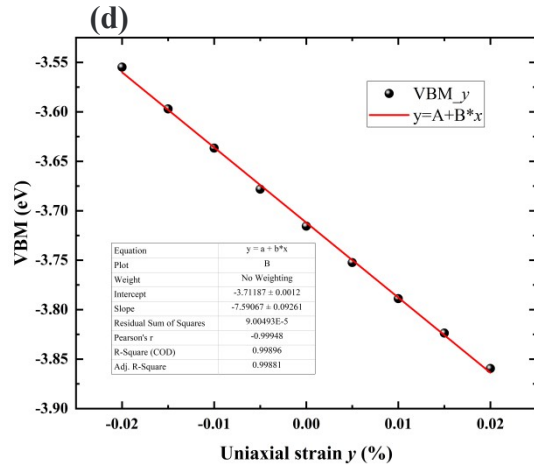
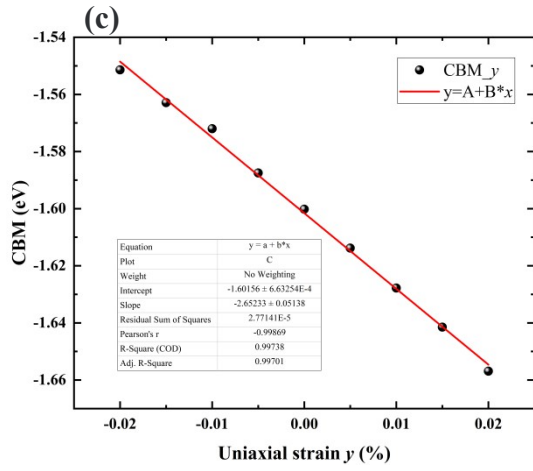
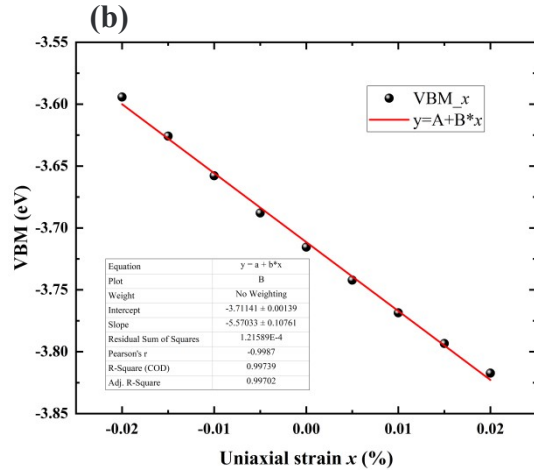
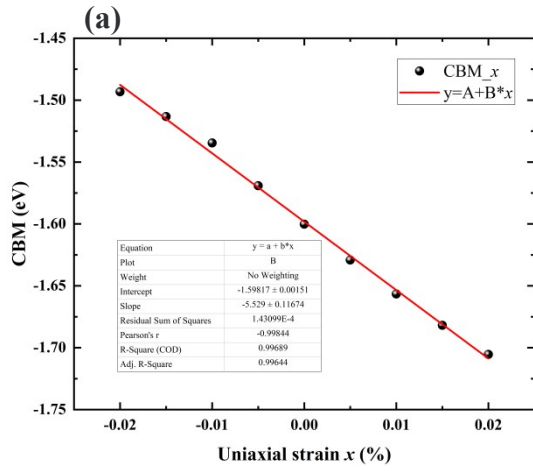


Fig. S5. The elastic modulus C_{2D} along the propagation direction is obtained through

the quadratic function fitting the total energy of the system under strain for monolayer ScScI in the (a) x - and (b) y -directions; for monolayer ScSBr in the (c) x - and (d) y -directions; for monolayer ScSeCl in the (e) x - and (f) y -directions; for monolayer ScSeBr in the (g) x - and (h) y -directions.



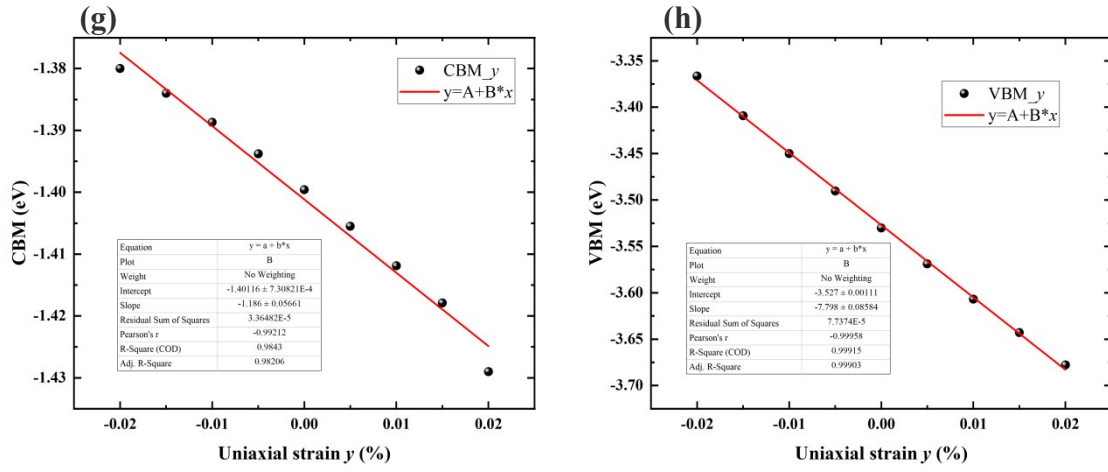


Fig. S6. Fitting the elastic modulus constant E_l for monolayer ScSCl: (a) x -axis uniaxial strained CBM, (b) x -axis uniaxial strained VBM, (c) y -axis uniaxial strained CBM and (d) y -axis uniaxial strained VBM; for monolayer ScSBr: (e) x -axis uniaxial strained CBM, (f) x -axis uniaxial strained VBM, (g) y -axis uniaxial strained CBM and (h) y -axis uniaxial strained VBM.

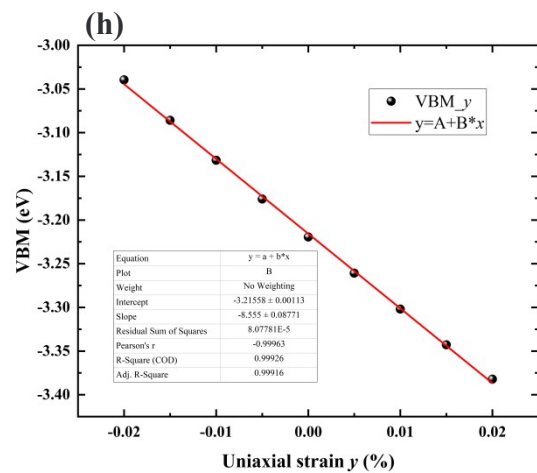
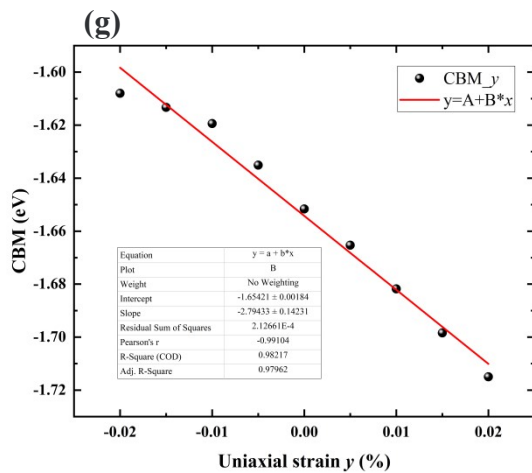
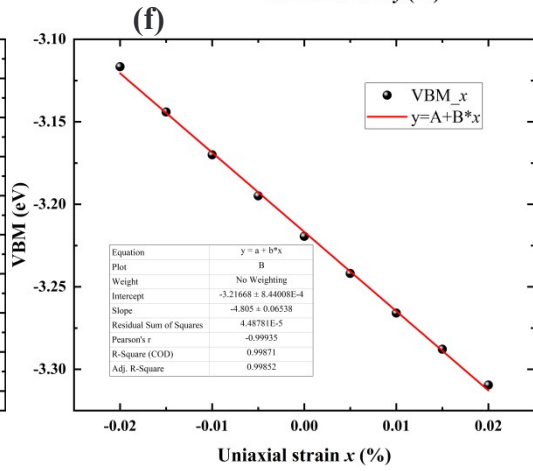
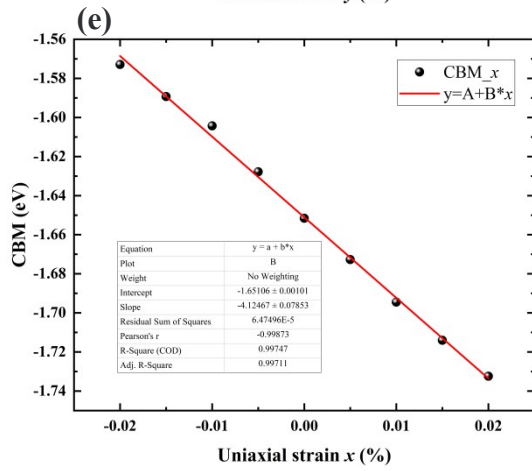
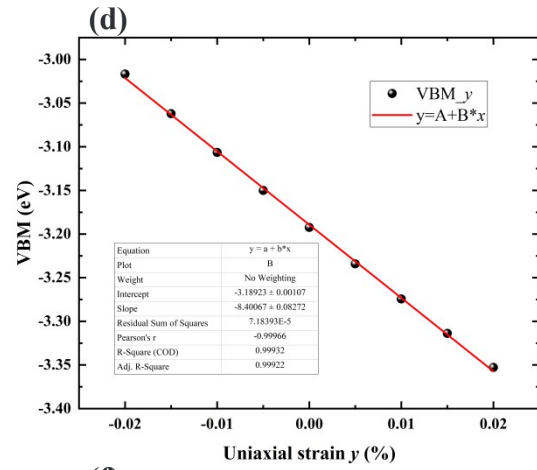
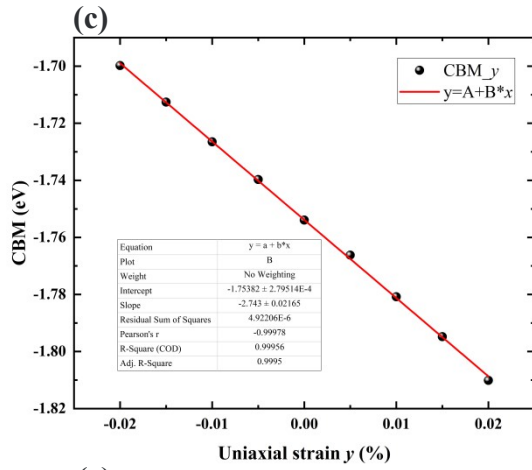
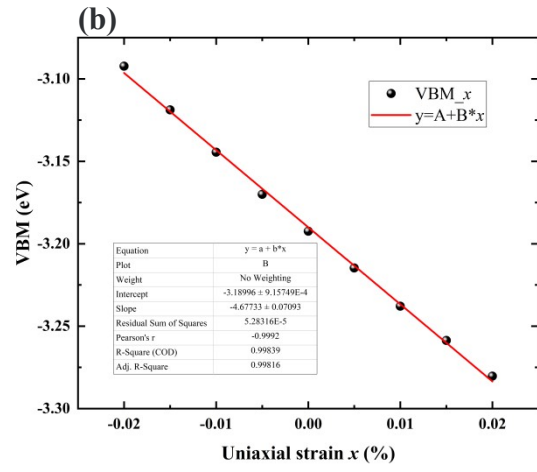
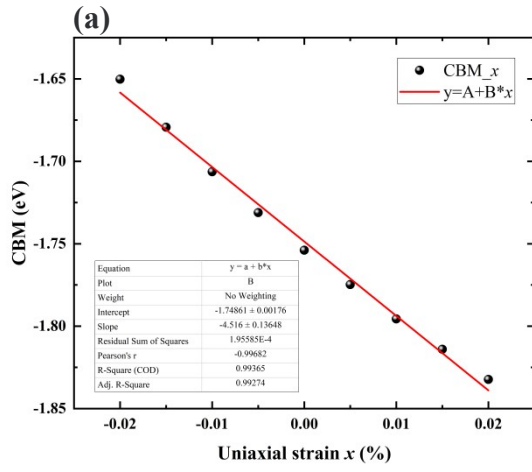


Fig S7. Fitting the elastic modulus constant E_l for monolayer ScSeCl: (a) x -axis uniaxial strained CBM, (b) x -axis uniaxial strained VBM, (c) y -axis uniaxial strained CBM and (d) y -axis uniaxial strained VBM; for monolayer ScSeBr: (e) x -axis uniaxial strained CBM, (f) x -axis uniaxial strained VBM, (g) y -axis uniaxial strained CBM and (h) y -axis uniaxial strained VBM.